

Interference

	Type	L #	Hits	Search Text
1	BRS	L45	44606	(semiconductor same (order or purchase\$3))"." and (semiconductor same design\$3)
2	BRS	L46	11792	(semiconductor same (order or purchase\$3)) and (semiconductor same design\$3)
3	BRS	L47	739	(semiconductor same (order or purchase\$3)) and (semiconductor same design\$3) and ((purcha\$3 or order\$3) same Intranet or Internet)
4	BRS	L48	739	(semiconductor same (order or purchase\$3)) and (semiconductor same design\$3) and ((purcha\$3 or order\$3) same Intranet or Internet)
5	BRS	L49	653	(semiconductor same (order or purchase\$3)) and (semiconductor same design\$3) and ((purcha\$3 or order\$3) same Intranet or Internet) and circuit
6	BRS	L50	155	(semiconductor same (order or purchase\$3)) and (semiconductor same design\$3) and ((purcha\$3 or order\$3) same Intranet or Internet) and (circuit adj design)
7	BRS	L51	0	(semiconductor same (order or purchase\$3)) and (semiconductor same design\$3) and ((purcha\$3 or order\$3) same Intranet or Internet) and (circuit adj design) and (character adj projection)

TS

3/5/06



semiconductor "Shunko Magoshi"

Search

[Advanced Scholar Search](#)
[Scholar Preferences](#)
[Scholar Help](#)
ScholarResults 1 - 4 of 4 for semiconductor "Shunko Magoshi". (0.04 seconds)

Tip: Try removing quotes from your search to get more results.

Improved Electron-Beam/Deep-Ultraviolet Intralevel Mix-and-Match Lithography with 100 nm Resolution

S Magoshi, H Niiyama, S Sato, Y Kato, Y Watanabe, ... - Jpn. J. Appl. Phys, 1999 - jjap.ipap.jp

... **Shunko Magoshi**, Hiromi Niiyama, Shinji Sato, Yoshimitsu Kato, Yumi Watanabe, Tohru ...

Fabricating Sub-100-nm Complementary Metal-Oxide-Semiconductor Devices using ...

[Cited by 1](#) - [Cached](#) - [Web Search](#) - [BL Direct](#)

High-speed electron beam data conversion system combining hierarchical operation with parallel ... - group of 2 »

S Magoshi, K Koyama, O Ikenaga, S Watanabe, T ... - JPN J APPL PHYS PART 1 REGUL PAP SHORT NOTE., 1992 - csa.com

Shunko Magoshi, Kiyomi Koyama, Osamu Ikenaga, Susumu Watanabe, Tamaki Saito, ShinjiSakamoto, Shin-ichiro ... 2 **Semiconductor** Devices and Integrated Circuits; E 932 ...[Web Search](#) - [BL Direct](#)

Throughput Enhancement Strategy of Maskless Electron Beam Direct Writing for Logic Device - group of 2 »

R Inanami, S Magoshi, S Kousai, M Hamada, T ... - INTERNATIONAL ELECTRON DEVICES MEETING, 2000 - ieeexplore.ieee.org

... Ryoichi Inanami, **Shunko Magoshi**, Shohei Kousai", Mototsugu Hamada", ToshinariTakayanagi ... bess & Manufacturing Engineering Center, **Semiconductor** Company, Toshiba ...[Web Search](#) - [BL Direct](#)

Stress-Induced Voiding Phenomena for an actual CMOS LSI Interconnects

H NAKAZAWA, M MORITA - ieeexplore.ieee.org

... **Semiconductor** Company. ... Ms. Sachiyo Itoh. Mr. **Shunko Magoshi**, and Mr. Masayuki Hatano

in TOSHIBA Corporation for their help with the experiment and discussion. ...

[Web Search](#)

semiconductor "Shunko Magoshi"

Search

[Google Home](#) - [About Google](#) - [About Google Scholar](#)

©2006 Google



semiconductor design network "Katsuya Okun"

Search

[Advanced Scholar Search](#)[Scholar Preferences](#)[Scholar Help](#)**Scholar**Results 1 - 2 of 2 for semiconductor design network "Katsuya Okumura". (0.05 seconds)

Tip: Try removing quotes from your search to get more results.

Silicon Interposer Technology for High-Density Package - group of 2 »M Matsuo, N Hayasaka, K Okumura, E Hosomi, C ... - ELECTRONIC COMPONENTS AND TECHNOLOGY CONFERENCE, 2000 - [ieeexplore.ieee.org](#)... jp **Advanced Packaging Engineering Depart., **Semiconductor** Company, Toshiba ... in turn, leads to shrinking **design** rule of ... probes and an HP-8720D **network** analyzer. ...[Cited by 1](#) - [Web Search](#) - [BL Direct](#)High-density plasma chemical vapor deposition of silicon-based dielectric films for integrated ... - group of 3 »SV Nguyen - IBM JOURNAL OF RESEARCH AND DEVELOPMENT, 1999 - [research.ibm.com](#)... Besides parameters associated with the **design** of the ... the formation of a porous oxide **network** and hole ... to thank the IBM Advanced **Semiconductor** Technology Center ...[Cited by 8](#) - [Cached](#) - [Web Search](#) - [BL Direct](#)

semiconductor design network "Kats"

Search

[Google Home](#) - [About Google](#) - [About Google Scholar](#)

©2006 Google



Welcome United States Patent and Trademark Office

Search Results

[BROWSE](#)[SEARCH](#)[IEEE XPLORE GUIDE](#)

Results for "(inunami r.<in>au)"

Your search matched 4 of 1322957 documents.

A maximum of 100 results are displayed, 25 to a page, sorted by Relevance in Descending order.



» Search Options

[View Session History](#)[New Search](#)

Modify Search

(inunami r.<in>au)

[Search](#)☐ Check to search only within this results setDisplay Format: ☒ Citation ☐ Citation & Abstract

» Key

IEEE JNL IEEE Journal or Magazine

IEE JNL IEE Journal or Magazine

IEEE CNF IEEE Conference Proceeding

IEE CNF IEE Conference Proceeding

IEEE STD IEEE Standard

[view selected items](#)[Select All](#) [Deselect All](#)

- ☐ 1. **Cell Library Development Methodology for Throughput Enhancement of Direct-Write Lithography Systems**
Sugihara, M.; Takata, T.; Nakamura, K.; Inanami, R.; Hayashi, H.; Kishimoto, K.; Kawano, Y.; Matsunaga, Y.; Murakami, K.; Okumura, K.;
[System-on-Chip, 2005. Proceedings. 2005 International Symposium on](#)
15-17 Nov. 2005 Page(s):137 - 140
[AbstractPlus](#) | Full Text: [PDF](#)(1904 KB) IEEE CNF
[Rights and Permissions](#)
- ☐ 2. **A study of line edge roughness in chemically amplified resist for low energy beam lithography**
Nakasugi, T.; Ando, A.; Inanami, R.; Sasaki, N.; Sugihara, K.;
[Microprocesses and Nanotechnology Conference, 2001 International](#)
31 Oct.-2 Nov. 2001 Page(s):302 - 303
Digital Object Identifier 10.1109/IMNC.2001.984209
[AbstractPlus](#) | Full Text: [PDF](#)(269 KB) IEEE CNF
[Rights and Permissions](#)
- ☐ 3. **Throughput enhancement strategy of maskless electron beam direct write device**
Inanami, R.; Magoshi, S.; Kousai, S.; Hmada, M.; Takayanagi, T.; Sugihara, K.; Kuroda, T.;
[Electron Devices Meeting, 2000. IEDM Technical Digest. International](#)
10-13 Dec. 2000 Page(s):833 - 836
Digital Object Identifier 10.1109/IEDM.2000.904446
[AbstractPlus](#) | Full Text: [PDF](#)(312 KB) IEEE CNF
[Rights and Permissions](#)
- ☐ 4. **Lithography simulator for EB/DUV Intra-level mix and match**
Inanami, R.; Nakasugi, T.; Sato, S.; Mimotogi, S.; Tanaka, S.; Sugihara, K.;
[Microprocesses and Nanotechnology Conference, 1999. Digest of Papers. Mic](#)
[Nanotechnology '99. 1999 International](#)
6-8 July 1999 Page(s):38 - 39
Digital Object Identifier 10.1109/IMNC.1999.797465
[AbstractPlus](#) | Full Text: [PDF](#)(140 KB) IEEE CNF
[Rights and Permissions](#)

[Help](#) [Contact Us](#) [Privacy & :](#)

© Copyright 2006 IEEE –

indexed by
 Inspec



Welcome United States Patent and Trademark Office

Search Results

[BROWSE](#)[SEARCH](#)[IEEE XPLORE GUIDE](#)

Results for "(magoshi s.<in>au)"

Your search matched 6 of 1322957 documents.

A maximum of 100 results are displayed, 25 to a page, sorted by **Relevance** in **Descending** order.

» Search Options

[View Session History](#)[New Search](#)

Modify Search

☐ Check to search only within this results setDisplay Format: ☒ Citation ☐ Citation & Abstract

» Key

IEEE JNL IEEE Journal or Magazine

IEE JNL IEE Journal or Magazine

IEEE CNF IEEE Conference Proceeding

IEE CNF IEE Conference Proceeding

IEEE STD IEEE Standard

[view selected items](#)[Select All](#) [Deselect All](#)

- ☐ 1. **A hp22 nm node low operating power (LOP) technology with sub-10 nm g planar bulk CMOS devices**
Yasutake, N.; Ohuchi, K.; Fujiwara, M.; Adachi, K.; Hokazono, A.; Kojima, K.; Watanabe, T.; Morooka, T.; Mizuno, H.; Magoshi, S.; Shimizu, T.; Mori, S.; Ogi, T.; Ohmura, M.; Miyano, K.; Yamada, H.; Tomita, H.; Matsushita, D.; Muraoka, Takayanagi, M.; Ishimaru, K.; Ishiuchi, H.;
[VLSI Technology, 2004. Digest of Technical Papers. 2004 Symposium on 15-17 June 2004 Page\(s\):84 - 85](#)
Digital Object Identifier 10.1109/VLSIT.2004.1345407
[AbstractPlus](#) | Full Text: [PDF\(276 KB\)](#) [IEEE CNF](#)
[Rights and Permissions](#)
- ☐ 2. **14 nm gate length CMOSFETs utilizing low thermal budget process with salicide**
Hokazono, A.; Ohuchi, K.; Takayanagi, M.; Watanabe, Y.; Magoshi, S.; Kato, Y.; Mori, S.; Oguma, H.; Sasaki, T.; Yoshimura, H.; Miyano, K.; Yasutake, N.; Sutoh, H.; Watanabe, T.; Tamaoki, N.; Toyoshima, Y.; Ishiuchi, H.;
[Electron Devices Meeting, 2002. IEDM '02. Digest. International 8-11 Dec. 2002 Page\(s\):639 - 642](#)
Digital Object Identifier 10.1109/IEDM.2002.1175920
[AbstractPlus](#) | Full Text: [PDF\(324 KB\)](#) [IEEE CNF](#)
[Rights and Permissions](#)
- ☐ 3. **High performance 35 nm gate length CMOS with NO oxynitride gate dielectric**
Inaba, S.; Okano, K.; Matsuda, S.; Fujiwara, M.; Hokazono, A.; Adachi, K.; Ohno, H.; Shimizu, T.; Mori, S.; Oguma, H.; Murakoshi, A.; Itani, T.; Inuma, T.; Shibata, H.; Taniguchi, S.; Matsushita, T.; Magoshi, S.; Watanabe, Y.; Takayanagi, A.; Oyamatsu, H.; Suguro, K.; Katsumata, Y.; Toyoshima, Y.; Ishiuchi, H.;
[Electron Devices Meeting, 2001. IEDM Technical Digest. International 2-5 Dec. 2001 Page\(s\):29.6.1 - 29.6.4](#)
Digital Object Identifier 10.1109/IEDM.2001.979590
[AbstractPlus](#) | Full Text: [PDF\(311 KB\)](#) [IEEE CNF](#)
[Rights and Permissions](#)
- ☐ 4. **Throughput enhancement strategy of maskless electron beam direct write device**
Inanami, R.; Magoshi, S.; Kousai, S.; Hmada, M.; Takayanagi, T.; Sugihara, K.; Kuroda, T.;

[Electron Devices Meeting, 2000. IEDM Technical Digest. International](#)
10-13 Dec. 2000 Page(s):833 - 836
Digital Object Identifier 10.1109/IEDM.2000.904446
[AbstractPlus](#) | Full Text: [PDF](#)(312 KB) [IEEE CNF](#)
[Rights and Permissions](#)

- ☐ **5. Improved Electron-Beam / DUV Intra-Level Mix-and-Match As A Productic Lithography With 100-nm Resolution**
Magoshi, S.; Niiyama, H.; Sato, S.; Kato, Y.; Watanabe, Y.; Shibata, T.; Ito, M. Nakasugi, T.; Sugihara, K.; Okumura, K.;
[Microprocesses and Nanotechnology Conference, 1998 International](#)
13-16 July 1998 Page(s):42 - 43
[AbstractPlus](#) | Full Text: [PDF](#)(132 KB) [IEEE CNF](#)
[Rights and Permissions](#)
- ☐ **6. Charge Reducing Effect Of Chemically Amplified Resist**
Nakasugi, T.; Magoshi, S.; Sugihara, K.; Saito, S.; Kihara, N.;
[Microprocesses and Nanotechnology Conference, 1998 International](#)
13-16 July 1998 Page(s):338 - 339
[AbstractPlus](#) | Full Text: [PDF](#)(144 KB) [IEEE CNF](#)
[Rights and Permissions](#)

[Help](#) [Contact Us](#) [Privacy & :](#)

© Copyright 2006 IEEE -

Indexed by
 Inspec[®]

[Home](#) | [Login](#) | [Logout](#) | [Access Information](#) | [Alerts](#) |

Welcome United States Patent and Trademark Office

Search Results**BROWSE****SEARCH****IEEE XPLORE GUIDE**

Results for "((okumura<and>semiconductor<and>retail)<in>metadata)"

Your search matched **0** documents.A maximum of **100** results are displayed, **25** to a page, sorted by **Relevance** in **Descending** order.» **Search Options**[View Session History](#)[New Search](#)**Modify Search**☐ Check to search only within this results set**Display Format:** ☒ Citation ☐ Citation & Abstract» **Key****IEEE JNL** IEEE Journal or Magazine**IEE JNL** IEE Journal or Magazine**IEEE CNF** IEEE Conference Proceeding**IEE CNF** IEE Conference Proceeding**IEEE STD** IEEE Standard**No results were found.**

Please edit your search criteria and try again. Refer to the Help pages if you need assistance.

[Help](#) [Contact Us](#) [Privacy & Policy](#)

© Copyright 2006 IEEE –



[Home](#) | [Login](#) | [Logout](#) | [Access Information](#) | [Alerts](#) |

Welcome United States Patent and Trademark Office

Search Results**BROWSE****SEARCH****IEEE XPLORE GUIDE**

Results for "((okumura<and>semiconductor<and>information)<in>metadata)"

Email

Your search matched 0 documents.

A maximum of 100 results are displayed, 25 to a page, sorted by **Relevance** in **Descending** order.

» Search Options

[View Session History](#)[New Search](#)**Modify Search**

Search

☐ Check to search only within this results setDisplay Format: ☒ Citation ☐ Citation & Abstract

» Key

IEEE JNL IEEE Journal or Magazine

IEE JNL IEE Journal or Magazine

IEEE CNF IEEE Conference Proceeding

IEE CNF IEE Conference Proceeding

IEEE STD IEEE Standard

No results were found.

Please edit your search criteria and try again. Refer to the Help pages if you need assistance search.

Indexed by
 Inspec[Help](#) [Contact Us](#) [Privacy & :](#)

© Copyright 2006 IEEE –

Recent Searches

[Close window](#) | [Help](#)Add terms to your search using:

3. author(Katsuya Okumura)
Database: ProQuest Dissertations and Theses - Full Text
Look for terms in: Citation and abstract
Publication type: All publication types
2. author(Shunko Magoshi)
Database: ProQuest Dissertations and Theses - Full Text
Look for terms in: Citation and abstract
Publication type: All publication types
1. author(Ryoichi Inanami)
Database: ProQuest Dissertations and Theses - Full Text
Look for terms in: Citation and abstract
Publication type: All publication types

0 result [Set Up Alert](#)0 result [Set Up Alert](#)0 result [Set Up Alert](#)[Close window](#) | [Help](#)

	Type	L #	Hits	Search Text
1	BRS	L9	163954	(semiconductor same (order\$3 or purchas\$3))
2	BRS	L10	7043	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet))
3	BRS	L11	505	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2)
4	BRS	L12	116	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2)
5	BRS	L13	0	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and (circuit\$2 near patern\$2)
6	BRS	L14	0	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and patern
7	BRS	L15	88	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern
8	BRS	L16	0	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern and (character adj projection)
9	BRS	L17	88	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern and cost
10	BRS	L18	15	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern and cost and deliver\$3

	DBs	Time Stamp	Comments	Error Definition
1	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:29		
2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:30		
3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:31		
4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:31		
5	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:32		
6	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:32		
7	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:32		
8	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:33		
9	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:33		
10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:40		

	Type	L #	Hits	Search Text
11	BRS	L19	3	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern and cost and deliver\$3 and aperture
12	BRS	L20	0	707/103.ccls.
13	BRS	L21	725	703/6.ccls.
14	BRS	L22	511	(character adj projection)
15	BRS	L23	8	(character adj projection) same (internet or intranet or network)
16	BRS	L24	51	(character adj projection) same (semiconduct\$2)
17	BRS	L25	0	(character adj projection) same (semiconduct\$2) same (internet or netork)
18	BRS	L26	316	703/6.ccls.and network
19	BRS	L27	332	703/6.ccls.and (network or Internet or Intranet)
20	BRS	L28	68	703/6.ccls.and (network or Internet or Intranet) and semiconductor
21	BRS	L29	40	703/6.ccls.and (network or Internet or Intranet) and semiconductor and circuits
22	BRS	L30	3	703/6.ccls.and (network or Internet or Intranet) and semiconductor and circuits and aperture

	DBs	Time Stamp	Comments	Error Definition
11	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:36		
12	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:40		
13	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:42		
14	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:41		
15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:42		
16	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:42		
17	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:42		
18	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:43		
19	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:43		
20	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:43		
21	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:43		
22	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	2006/03/05 12:43		

	Type	L #	Hits	Search Text
1	BRS	L9	163954	(semiconductor same (order\$3 or purchas\$3))
2	BRS	L10	7043	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet))
3	BRS	L11	505	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2)
4	BRS	L12	116	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2)
5	BRS	L13	0	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and (circuit\$2 near patern\$2)
6	BRS	L14	0	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and patern
7	BRS	L15	88	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern
8	BRS	L16	0	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern and (character adj projection)
9	BRS	L17	88	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern and cost
10	BRS	L18	15	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern and cost and deliver\$3

	Type	L #	Hits	Search Text
11	BRS	L19	3	(semiconductor same (order\$3 or purchas\$3)) and ((order\$3 or purchas\$4) same (network or Internet or Intranet)) and ((Internet or network) same customer\$2) and (semiconductor\$2 same specification\$2) and pattern and cost and deliver\$3 and aperture
12	BRS	L20	0	707/103.ccls.
13	BRS	L21	725	703/6.ccls.
14	BRS	L22	511	(character adj projection)
15	BRS	L23	8	(character adj projection) same (internet or intranet or network)
16	BRS	L24	51	(character adj projection) same (semiconduct\$2)
17	BRS	L25	0	(character adj projection) same (semiconduct\$2) same (internet or netork)
18	BRS	L26	316	703/6.ccls.and network
19	BRS	L27	332	703/6.ccls.and (network or Internet or Intranet)
20	BRS	L28	68	703/6.ccls.and (network or Internet or Intranet) and semiconductor
21	BRS	L29	40	703/6.ccls.and (network or Internet or Intranet) and semiconductor and circuits
22	BRS	L30	3	703/6.ccls.and (network or Internet or Intranet) and semiconductor and circuits and aperture
23	BRS	L31	0	(program adj product) and (semiconductor adj device) and ((order\$ or purchas\$3) same (Internet same Intranet same network))
24	BRS	L32	1216	(program adj product) and (semiconductor adj device)
25	BRS	L33	7	(program adj product) and (semiconductor adj device) and (purchase same (network or Intranet))
26	BRS	L34	1	(program adj product) and (semiconductor adj device) and (purchase same (network or Intranet)) and (record\$3 same medium)
27	BRS	L35	4416	705/26.ccls.
28	BRS	L36	360	705/26.ccls. and semiconductors
29	BRS	L37	4	705/26.ccls. and (semiconductors adj design\$3)
30	BRS	L38	1	705/26.ccls. and (program adj product) and (semiconductor adj device) and (purchase same (network or Intranet)) and (record\$3 same medium)